#### TOSHIBA Field Effect Transistor with Built-in Schottky Barrier Diode Silicon N-Channel MOS Type (U-MOS V-H)

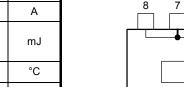
# TPCA8A08-H

High Efficiency DC-DC Converter Applications Notebook PC Applications Portable Equipment Applications

- Built-in a schottky barrier diode
   Low forward voltage: V<sub>DSF</sub> = -0.6 V (max)
- High-speed switching
- Small gate charge: Q<sub>SW</sub> = 11 nC (typ.)
- Low drain-source ON-resistance:
  - $R_{DS (ON)}$  = 3.8 m $\Omega$  (typ.) (V<sub>GS</sub> = 4.5 V)
- High forward transfer admittance: |Y<sub>fs</sub>| = 105 S (typ.)
- Low leakage current: I<sub>DSS</sub> = 100 μA (max) (V<sub>DS</sub> = 30 V)
- Enhancement mode:  $V_{th}$  = 1.3 to 2.3 V ( $V_{DS}$  = 10 V,  $I_D$  = 1 mA)

#### Absolute Maximum Ratings (Ta = 25°C)

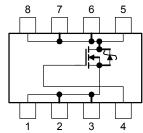
Characteristic		Symbol	Rating	Unit
Drain-source voltage		V <sub>DSS</sub>	30	(v)
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		VDGR	30	V
Gate-source voltage		VGSS	±20	V V
Drain current	DC (Note 1)		38	A
	Pulsed (Note 1)	NDP	114	
Drain power dissipation	on (Tc = 25°C)	PD	45	W
Drain power dissipation (t = 10 s) (Note 2a)		PD	2,8	w
Drain power dissipation (t = 10 s) (Note 2b)		PD	1.6	W
Single-pulse avalanche energy (Note 3)		EAS	188	mJ
Avalanche current		IAR	38	А
Repetitive avalanche energy (Tc = 25°C) (Note 4)		EAR	2.57	mJ
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C



Unit: mm 1,27 0.4 ± 0.1 + 0.2  $0.15 \pm 0.05$ ש⊾ם ע 0.595 A 02  $5.0 \pm 0.2$ Q 0.05 S  $4.25 \pm 0.2$ 1,2,3: SOURCE 0.8±0. 4: GATE 5,6,7,8: DRAIN JEDEC JEITA TOSHIBA 2-5Q1A

Weight: 0.069 g (typ.)

#### **Circuit Configuration**



Note: For Notes 1 to 4, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability

temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

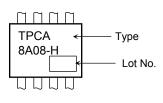
This transistor is an electrostatic-sensitive device. Handle with care.

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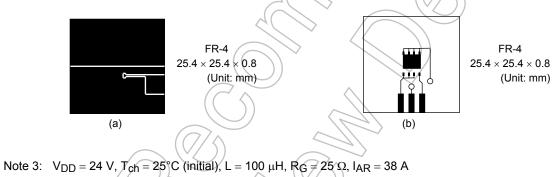
#### **Thermal Characteristics**

Characteristic	Symbol	Max	Unit	
Thermal resistance, channel to case (Tc = 25°C)	R <sub>th (ch-c)</sub>	2.78	°C/W	
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R <sub>th (ch-a)</sub>	44.6	°C/W	
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R <sub>th (ch-a)</sub>	78.1	°C/W	

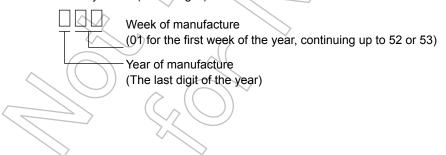
#### Marking (Note 5)



- Note 1: Ensure that the channel temperature does not exceed 150°C.
- Note 2: (a) Device mounted on a glass-epoxy board (a)
- (b) Device mounted on a glass-epoxy board (b)



- Note 4: Repetitive rating: pulse width limited by maximum channel temperature
- Note 5: \* Weekly code: (Three digits)



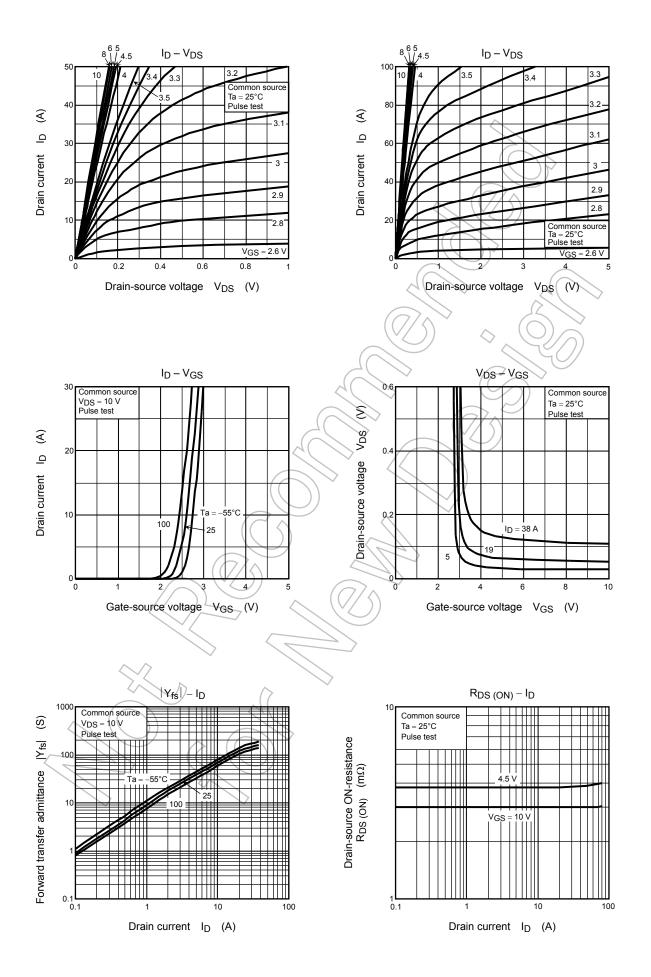
**Electrical Characteristics (Ta = 25°C)** 

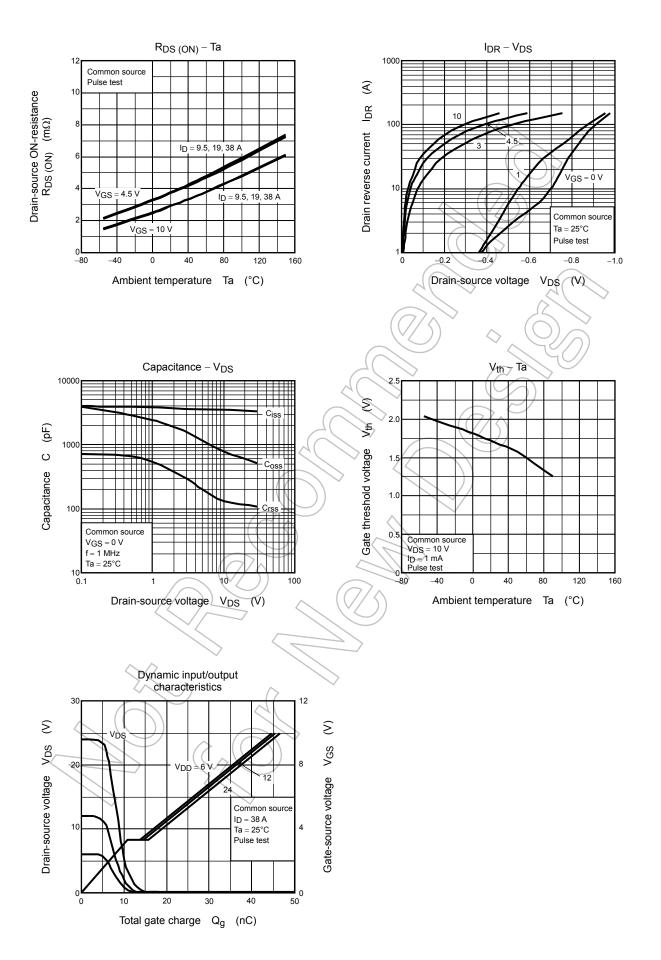
Ch	aracteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I <sub>GSS</sub>	$V_{GS}=\pm 20~V,~V_{DS}=0~V$	_	—	±100	nA
Drain cutoff curre	nt	I <sub>DSS</sub>	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_		100	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	30	_	_	v
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	15	1	_	v
Gate threshold vo	bltage	V <sub>th</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	1.3	)/	2.3	V
Drain-source ON-resistance		R <sub>DS (ON)</sub>	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 19 \text{ A}$	77	3.8	5.3	mΩ
			V <sub>GS</sub> = 10 V, I <sub>D</sub> = 19 A	Ĥ	3.0	4.2	
Forward transfer	admittance	Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 19 \text{ A}$	53	105	_	S
Input capacitance		C <sub>iss</sub>		_	3500	4600	
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	120	180	pF
Output capacitance		C <sub>oss</sub>		_	780	$\searrow$	
Gate resistance		rg	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 5 \text{ MHz}$	-6	1.0	1.5	Ω
Switching time	Rise time	tr	$I_D = 19 A$	X	4,6	) _	
	Turn-on time	t <sub>on</sub>		$\widehat{\mathcal{A}}$	14	_	ns
	Fall time	t <sub>f</sub>			7.9	_	
	Turn-off time	toff	$V_{DD} \approx 15 V$ Duty $\leq 1\%$ , t <sub>w</sub> = 10 µs	_	45	_	
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \approx 24$ V, $V_{GS} = 10$ V, $I_D = 38$ A	_	48	_	
			$V_{DD} \approx 24 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 38 \text{ A}$	_	24	_	
Gate-source char	rge 1	Q <sub>gs1</sub>			11	_	nC
Gate-drain ("Miller") charge		Qgd	$V_{DD} \approx 24 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 38 \text{ A}$	_	5.5	_	
Gate switch charge		QSW		_	11	_	

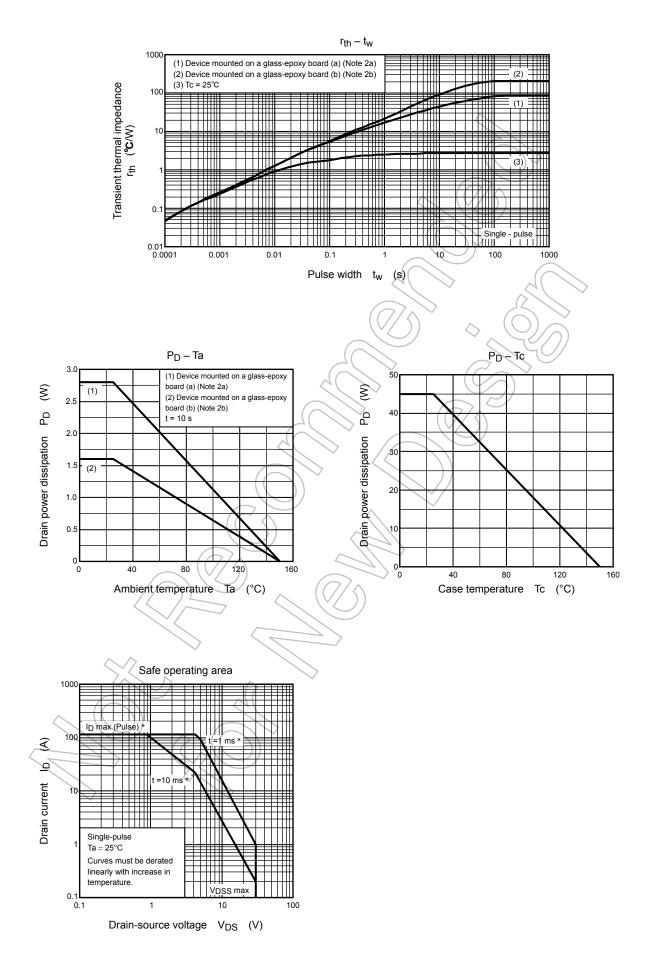
# Source-Drain Ratings and Characteristics (Ta = $25^{\circ}$ C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current Pulse (Note 1)	I <sub>DRP</sub>	> -		_	114	А
Forward valtage (digta)		I <sub>DR</sub> = 1 A, V <sub>GS</sub> = 0 V	_	- 0.4	- 0.6	V
Forward voltage (diode)	VDSF	I <sub>DR</sub> = 38 A, V <sub>GS</sub> = 0 V		_	- 1.2	V

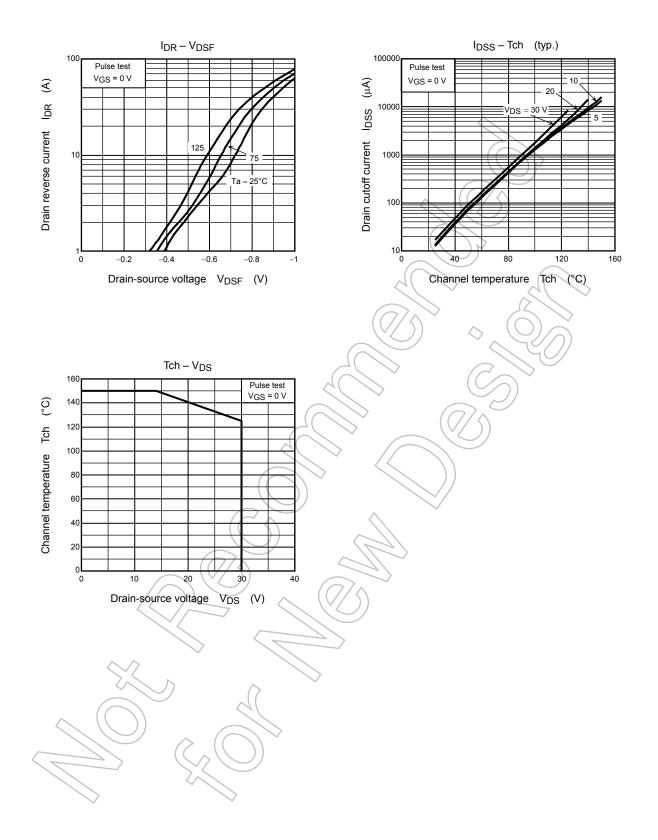
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